



11/15/01

438	155
Class	Subclass
ISSUE CLASSIFICATION	

PATENT NUMBER

U.S. UTILITY Patent Application

<p>O.I.P.E.</p> <p>FA</p> <p>SCANNED <u>LR</u> ⁽⁴⁾ Q.A. <u>W</u></p>	<p>PATENT DATE</p>
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$$\frac{3e^3}{3e^{895}}$$

APPLICATION NO.	CONT/PRIOR	CLASS	SUBCLASS	ART UNIT	EXAMINER
09/987607	D F	438	155	2813	HOGANS Davis

NTS Hongyong Zhang

79064

APPLICANTS

TITLE

Method for producing a semiconductor integrated circuit including a thin film transistor and a capacitor

PTO-2040
12/89[illegible]

**TERMINAL
DISCLAIMER**

☐ The term of this patent subsequent to _____ has been disclaimed.

☒ The term of this patent
not extend beyond the expiry
of U.S Patent. No. 5,814

☐ The terminal ____ months of the term of this patent have been disclaimed.

DRAWINGS			CLAIMS ALLOWED	
Sheets Drwg.	Figs. Drwg.	Print Fig.	Total Claims	Print Claim for O.G.
			NOTICE OF ALLOWANCE MAILED	
_____ (Assistant Examiner)				
_____ (Date)				
			ISSUE FEE	
			Amount Due	Date Paid
_____ (Primary Examiner)				
_____ (Date)				
			ISSUE BATCH NUMBER	
_____ (Legal Instruments Examiner)				
_____ (Date)				

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ISSUE FEE IN FILE

Formal Drawings (____ shts) set

(FACE)